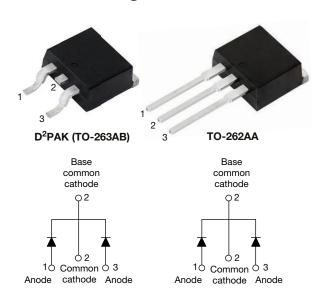


VS-48CTQ060S-M3

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High Performance Schottky Rectifiers, 2 x 20 A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 20 A				
V_{R}	60 V				
V _F at I _F	0.58 V				
I _{RM} typ.	89 mA at 125 °C				
T _J max.	150 °C				
E _{AS}	13 mJ				
Package	D ² PAK (TO-263AB), TO-262AA				
Circuit configuration	Common cathode				

VS-48CTQ060-1-M3

FEATURES

- 150 °C T_{.I} operation
- Center tap configuration
- Low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Rectangular waveform	40	Α					
V_{RRM}		60	V					
I _{FSM}	t _p = 5 μs sine	1000	Α					
V _F	20 A _{pk} , T _J = 125 °C (per leg)	0.58	V					
TJ	Range	-55 to +150	°C					

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-48CTQ060S-M3 VS-48CTQ060-1-M3 UNITS							
Maximum DC reverse voltage	V_{R}	60	V				
Maximum working peak reverse voltage	V_{RWM}	60	V				



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ABSOLUTE MAXIMUM RATINGS									
PARAMETER	PARAMETER		TEST CONDITIONS		VALUES	UNITS			
Maximum average per leg forward current See fig. 5 per device			50 % duty cycle at T _C = 111 °C, rectangular waveform		20	٨			
		I _{F(AV)}			40				
	Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load	1000	Α			
non-repetitive surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	260				
Non-repetitive avalanche energy per leg		E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.50 \text{A}, L = 11.5 \text{mH}$		13	mJ			
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T ₁ maximum V _A = 1.5 x V _P typical		1.50	Α			

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
		20 A	T _{.1} = 25 °C	0.61	V		
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	1j=25 C	0.83			
See fig. 1	VFM (1)	20 A	T _{.1} = 125 °C	0.58			
		40 A	1j = 125 C	0.75			
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_R = Rated V_R$	2	mA		
iviaximum reverse leakage current per leg		T _J = 125 °C	VR = nateu VR	140			
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V_R = Rated V_R	89	mA		
Threshold Voltage	$V_{F(TO)}$	T. –T. maximum		0.37	V		
Forward slope resistance	r _t	$T_J = T_J$ maximum		8.26	mΩ		
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		1220	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 mn	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

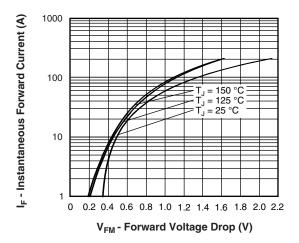
 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS			
Maximum junction and stor temperature range	age	T _J , T _{Stg}		-55 to +150	°C			
Maximum thermal resistance, junction to case per leg		D	DC operation	2.0				
Maximum thermal resistance, junction to case per package		- R _{thJC}	DC operation	1.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50				
Annyayimata wajaht				2	g			
Approximate weight				0.07	OZ.			
Mounting torque minimum maximum				6 (5)	kgf · cm			
				12 (10)	(lbf \cdot in)			
Marking device			Case style D ² PAK (TO-263AB)	48CTQ	060S			
			Case style TO-262AA	48CTQ	060-1			



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1000 T_{.1} = 150 °C I_R - Reverse Current (mA) 100 = 125 °C T_J = 100 °C 10 T₁ = 75 °C $T_J = \overline{50 \, ^{\circ}C}$ 0.1 $\dot{T}_1 = 25 \, ^{\circ}\dot{C}$ 0.01 0.001 10 50 30 0 40 60 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

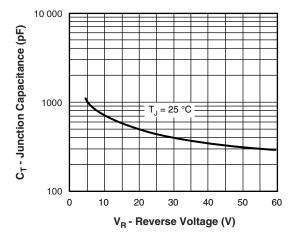


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

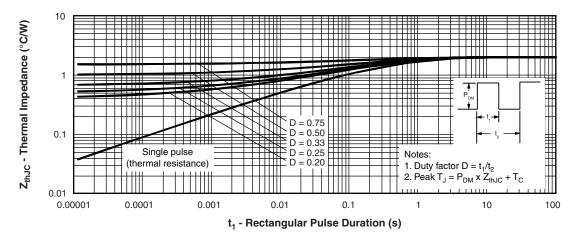


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)



Allowable Case Temperature (°C)

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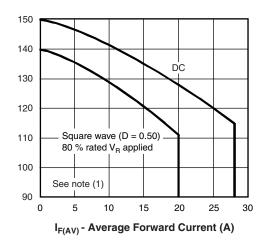


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

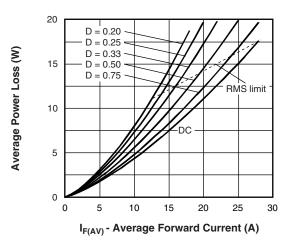


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

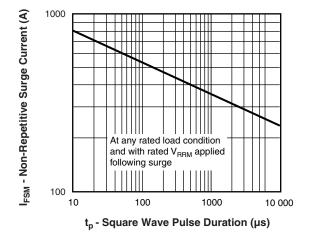


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

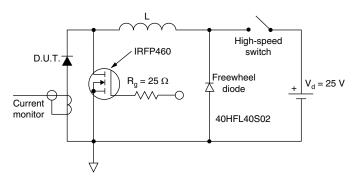


Fig. 8 - Unclamped Inductive Test Circuit

Note

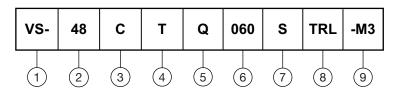
1) Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 10 V

VS-48CTQ060S-M3, VS-48CTQ060-1-M3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (40 A)

3 - Circuit configuration: C = common cathode

4 - T = TO-220

5 - Schottky "Q" series

Voltage rating (060 = 60 V)

7 - • S = D^2PAK (TO-263AB)

• -1 = TO-262AA

8 - • None = tube

• TRL = tape and reel (left oriented - for D²PAK (TO-263AB) only)

• TRR = tape and reel (right oriented - for D²PAK (TO-263AB) only)

9 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-48CTQ060S-M3	50	Antistatic plastic tubes					
VS-48CTQ060STRL-M3	800	13" diameter plastic tape and reel					
VS-48CTQ060STRR-M3	800	13" diameter plastic tape and reel					
VS-48CTQ060-1-M3	50	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS						
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164				
Differsions	TO-262AA	www.vishay.com/doc?96165				
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?96424				



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES		SYMBOL	MILLIMETERS		INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOIES	STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

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TO-262

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	METERS	INC	INCHES			
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06 4.83		0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
E	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54 BSC		0.100	BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.36	3.71	0.132	0.146			

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- 5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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